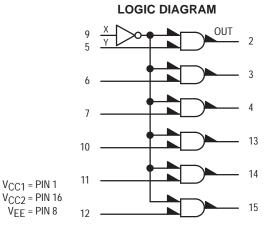
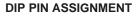
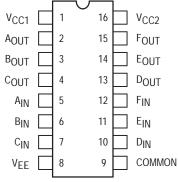
# **Hex Buffer With Enable**

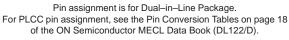
The MC10188 is a high–speed hex buffer with a common Enable input. When Enable is in the high state, all outputs are in the low state. When Enable is in the low state, the outputs take the same state as the inputs.

- Power Dissipation = 180 mW typ/pkg (No Load)
- Propagation Delay = 2.0 ns typ (B Q)
  2.5 ns typ (A Q)









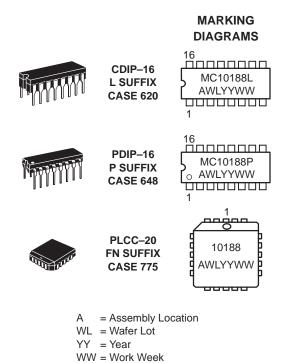
## TRUTH TABLE

Inputs		Output
Х	Y	OUT
L	L	L
L	Н	Н
Н	L	L
Н	Н	L



# **ON Semiconductor**

http://onsemi.com



## ORDERING INFORMATION

Device	Package	Shipping		
MC10188L	CDIP-16	25 Units / Rail		
MC10188P	PDIP-16	25 Units / Rail		
MC10188FN	PLCC-20	46 Units / Rail		

## MC10188

## ELECTRICAL CHARACTERISTICS

				Test Limits						
			Pin Under	-30	)°C	+2	5°C	+8	5°C	1
Characteris	Characteristic		Test	Min	Max	Min	Max	Min	Max	Unit
Power Supply Drain Cu	urrent	ΙE	8		46		42		46	mAdc
Input Current		l <sub>inH</sub>	5		425		265		265	μAdc
		linH	9		460		290		290	μAdc
Output Voltage	Logic 1	VOH	2	-1.060	-0.890	-0.960	-0.810	-0.890	-0.700	Vdc
Output Voltage	Logic 0	VOL	2	-1.890	-1.675	-1.850	-1.650	-1.825	-1.615	Vdc
Threshold Voltage	Logic 1	VOHA	2	-1.080		-0.980		-0.910		Vdc
Threshold Voltage	Logic 0	VOLA	2		-1.655		-1.630		-1.595	Vdc
Switching Times	(50 $\Omega$ Load)									ns
Propagation Delay	Enable Data	<sup>t</sup> PHL <sup>t</sup> PLH	2 2	1.1 1.0	3.9 3.3	1.1 1.0	3.5 2.9	1.1 1.0	3.9 3.3	
Rise/Fall Time	(20 to 80%)	<sup>t</sup> TLH <sup>t</sup> THL	2	1.1	3.7	1.1	3.3	1.1	3.7	

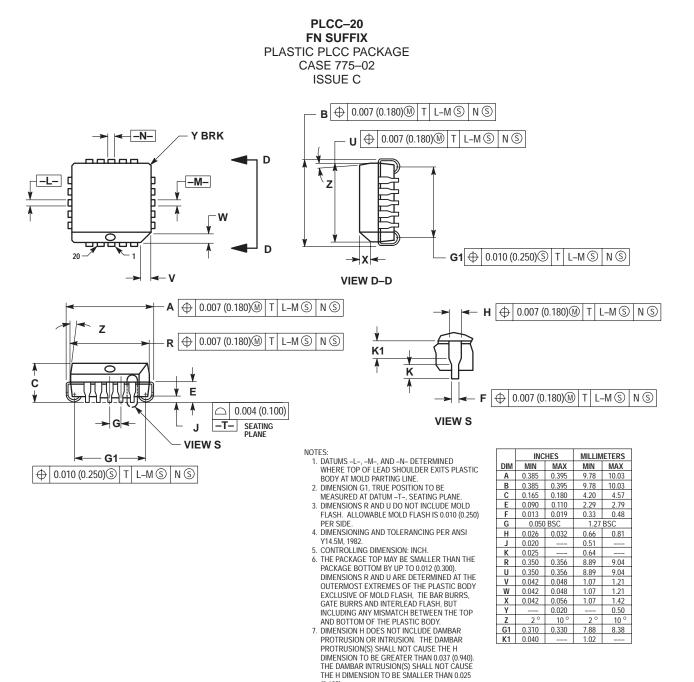
## ELECTRICAL CHARACTERISTICS (continued)

				TEST VOLTAGE VALUES (Volts)					
		@ Test Te	mperature	V <sub>IHmax</sub>	V <sub>ILmin</sub>	VIHAmin	V <sub>ILAmax</sub>	VEE	
			–30°C	-0.890	-1.890	-1.205	-1.500	-5.2	
			+25°C	-0.810	-1.850	-1.105	-1.475	-5.2	
			+85°C	-0.700	-1.825	-1.035	-1.440	-5.2	
Pin			TEST VOLTAGE APPLIED TO PINS LISTED BELOW						
Characteristic		Symbol	Under Test	V <sub>IHmax</sub>	V <sub>ILmin</sub>	V <sub>IHAmin</sub>	V <sub>ILAmax</sub>	V <sub>EE</sub>	(VCC) Gnd
Power Supply Drain Current		١E	8					8	1, 16
Input Current		l <sub>inH</sub>	5	5				8	1, 16
		l <sub>inH</sub>	9	9				8	1, 16
Output Voltage	Logic 1	VOH	2	5				8	1, 16
Output Voltage	Logic 0	VOL	2		9			8	1, 16
Threshold Voltage	Logic 1	VOHA	2			5		8	1, 16
Threshold Voltage	Logic 0	VOLA	2				5	8	1, 16
Switching Times	(50 $\Omega$ Load)					Pulse In	Pulse Out	–3.2 V	+2.0 V
Propagation Delay	Enable Data	<sup>t</sup> PHL <sup>t</sup> PLH	2 2			9 5	2 2	8 8	1, 16 1, 16
Rise/Fall Time	(20 to 80%)	<sup>t</sup> TLH <sup>t</sup> THL	2			5	2	8	1, 16

Each MECL 10,000 series circuit has been designed to meet the dc specifications shown in the test table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 linear fpm is maintained. Outputs are terminated through a 50–ohm resistor to –2.0 volts. Test procedures are shown for only one gate. The other gates are tested in the same manner.

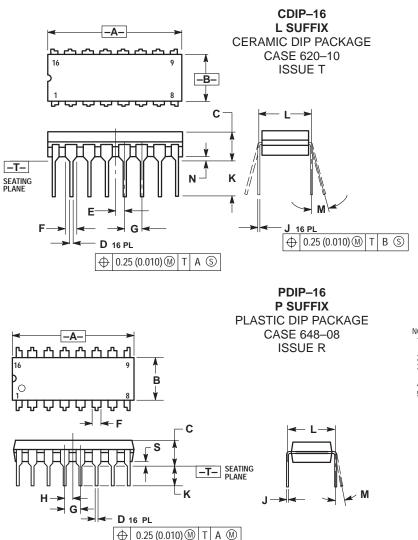
## MC10188

#### PACKAGE DIMENSIONS



(0.635).

## MC10188



#### NOTES:

DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

- CONTROLLING DIMENSION: INCH. DIMENSION L TO CENTER OF LEAD WHEN 3
- FORMED PARALLEL. DIMENSION F MAY NARROW TO 0.76 (0.030) 4
- WHERE THE LEAD ENTERS THE CERAMIC BODY

	INC	HES	MILLIMETERS		
DIM	MIN MAX		MIN	MAX	
Α	0.750	0.785	19.05	19.93	
В	0.240	0.295	6.10	7.49	
С		0.200		5.08	
D	0.015	0.020	0.39	0.50	
Е	0.050	) BSC	1.27 BSC		
F	0.055	0.065	1.40	1.65	
G	0.100 BSC		2.54 BSC		
Н	0.008	0.015	0.21	0.38	
К	0.125	0.170	3.18	4.31	
L	0.300 BSC		7.62 BSC		
Μ	0 °	15°	0 °	15 °	
Ν	0.020	0.040	0.51	1.01	

NOTES

- DIMENSIONING AND TOLERANCING PER ANSI 1
- Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
- DIMENSION B DOES NOT INCLUDE MOLD FLASH. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	IETERS	
DIM	MIN MAX		MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC 8	2.54 BSC		
Н	0.050 BSC		1.27 BSC		
J	0.008	0.015	0.21	0.38	
К	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
Μ	0°	10 °	0 °	10 °	
S	0.020	0.040	0.51	1.01	

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